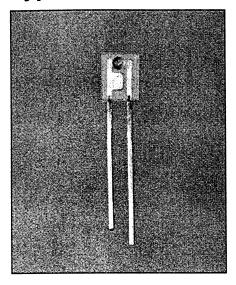
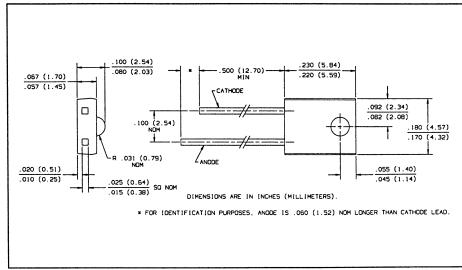
Product Bulletin OP240A June 1996



GaAlAs Plastic Infrared Emitting Diodes Types OP240A, OP240B, OP240C, OP240D





Features

- Wide irradiance pattern
- Mechanically and spectrally matched to the OP550 and OP560 series phototransistors
- Wavelength matched to silicon's peak response
- Significantly higher power output than GaAs at equivalent drive currents
- Side-looking package for space limited applications

Description

The OP240 series devices are 890nm high intensity gallium aluminum arsenide infrared emitting diodes molded in IR transmissive clear epoxy packages. The side-looking packages are for use in PC board mounted slotted switches or as easily mounted interrupt detectors.

Replaces

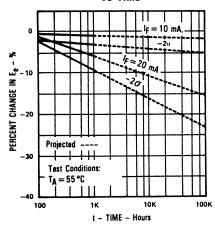
OP240SL series

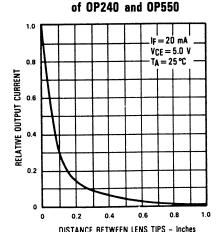
Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Peak Forward Current (1 μs pulse width, 300 pps) 3.0 A Storage and Operating Temperature Range -40° C to +100° C Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 sec. with soldering

- (1) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering. A max. of 20 grams force may be applied to the leads when soldering. (2) Derate linearly 1.33 mW/° C above 25° C.
- (3) E_{e(APT)} is a measurement of the average apertured radiant incidence upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (16.6 mm) from the lens tip. $E_{e(APT)}$ is not necessarily uniform within the

Typical Performance Curves **Percent Changes in Radiant Intensity** vs Time





Coupling Characteristics

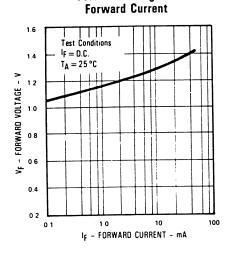
INFRARED EMITTING DIODES

Types OP240A, OP240B, OP240C, OP240D

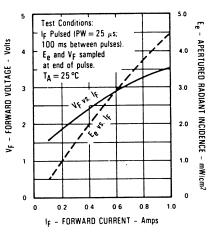
Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
E _{e(APT)}	Apertured Radiant Incidence OP240D	0.05			mW/cm ²	$I_F = 20 \text{ mA}_{(2)}^{(3)}$
-c(/ii 1)	OP240C	0.20		0.86	mW/cm ²	$I_F = 20 \text{ mA}_{(2)}^{(3)}$
	OP240B	0.40		1.20	mW/cm ²	$I_F = 20 \text{ mA}_{(2)}^{(3)}$
	OP240A	0.60			mW/cm ²	I _F = 20 mA ⁽³⁾
VF	Forward Voltage			1.80	V	I _F = 20 mA
I _R	Reverse Current			100	μΑ	V _R = 2 V
λр	Wavelength at Peak Emission		890		nm	I _F = 10 mA
В	Spectral Bandwidth Between Half Power Points		80		nm	I _F = 10 mA
Δλρ/ΔΤ	Spectral Shift with Temperature		+0.18		nm/° C	I _F = Constant
θнР	Emission Angle at Half Power Points		40		Deg.	I _F = 20 mA
tr	Output Rise Time		500		ns	$I_{F(PK)} = 100 \text{ mA},$
tf	Output Fall Time		250		ns	PW = 10 μs, D.C. = 10%

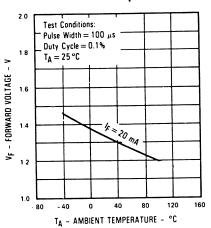




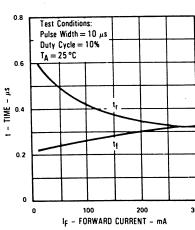
Forward Voltage and Radiant Incidence vs Forward Current



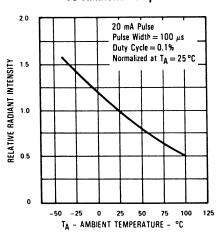
Forward Voltage vs Ambient Temperature



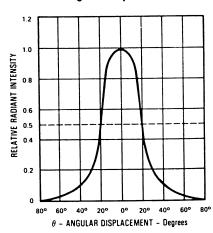




Relative Radiant Intensity vs Ambient Temperature



Relative Radiant Intensity vs Angular Displacement



Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.